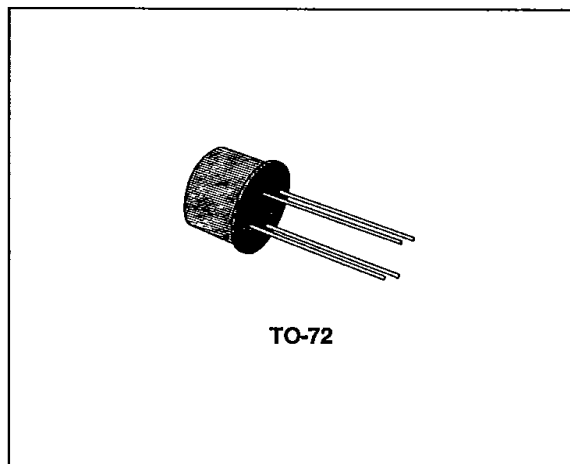


## WIDE BAND VHF/UHF AMPLIFIER

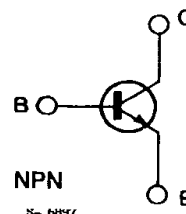
- SILICON PLANAR EPITAXIAL TRANSISTORS
- TO-72 METAL CASE
- VERY LOW NOISE

**APPLICATIONS :**

- TELECOMMUNICATIONS
- WIDE BAND UHF AMPLIFIER
- RADIO COMMUNICATIONS


**DESCRIPTION**

The BFX89 and BFY90 are silicon planar epitaxial NPN transistors produced using interdigitated base emitter geometry. They are particularly designed for use in wide band common-emitter linear amplifiers up to 1 GHz. They feature very high  $f_T$ , low reverse capacitance, excellent cross modulation properties and very low noise performance. The BFY90 is complementary to the BFR99A. Typical applications include telecommunication and radio communication equipment.

**INTERNAL SCHEMATIC DIAGRAM**

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	30	V
$V_{CER}$	Collector-emitter Voltage ( $R_{BE} \leq 50 \Omega$ )	30	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	15	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	2.5	V
$I_C$	Collector Current	25	mA
$I_{CM}$	Collector Peak Current ( $f \geq 1$ MHz)	50	mA
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25$ °C	200	mW
$T_{stg}, T_j$	Storage and Junction Temperature	- 65 to 200	°C

## THERMAL DATA

$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	580	°C/W
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max	880	°C/W

ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ °C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector Cutoff Current ( $I_E = 0$ )	$V_{CB} = 15\text{ V}$			10	nA
$V_{CEK}^*$	Collector-emitter Knee Voltage	$I_C = 20\text{ mA}$			0.75	V
$h_{FE}$	DC Current Gain	$I_C = 2\text{ mA}$ $V_{CE} = 1\text{ V}$ for <b>BFX89</b> for <b>BFY90</b> $I_C = 25\text{ mA}$ $V_{CE} = 1\text{ V}$	20 25 20		150 150 125	
$f_T$	Transition Frequency	$V_{CE} = 5\text{ V}$ $f = 500\text{ MHz}$ $I_C = 2\text{ mA}$ for <b>BFX89</b> for <b>BFY90</b> $I_C = 25\text{ mA}$ for <b>BFX89</b> for <b>BFY90</b>	1 1.3	1 1.1 1.2 1.4		GHz GHz GHz GHz
$C_{CBO}^{(1)}$	Collector-base Capacitance	$I_E = 0$ $V_{CB} = 10\text{ V}$ $f = 1\text{ MHz}$ for <b>BFX89</b> for <b>BFY90</b>			1.7 1.5	pF pF
$C_{re}^{(2)}$	Reverse Capacitance	$I_C = 2\text{ mA}$ $V_{CE} = 5\text{ V}$ $f = 1\text{ MHz}$ for <b>BFX89</b> for <b>BFY90</b>		0.6 0.6	0.8	pF pF
$NF^{(2)}$	Noise Figure	$I_C = 2\text{ mA}$ $V_{CE} = 5\text{ V}$ $R_g = \text{Optimized}$ $f = 100\text{ kHz}$ for <b>BFY90</b> Only $f = 200\text{ MHz}$ $R_g = \text{Optimized}$ for <b>BFX89</b> for <b>BFY90</b> $f = 500\text{ MHz}$ $R_g = 50\ \Omega$ for <b>BFX89</b> for <b>BFY90</b> $f = 800\text{ MHz}$ $R_g = \text{Optimized}$ for <b>BFX89</b> for <b>BFY90</b>			4 3.3 2.5 6.5 5 7 5.5	dB dB dB dB dB dB dB
$G_{pe}^{(2)}$	Power Gain (not neutralized)	for <b>BFX89</b> $I_C = 8\text{ mA}$ $V_{CE} = 10\text{ V}$ $f = 200\text{ MHz}$ $f = 800\text{ MHz}$ for <b>BFY90</b> $I_C = 14\text{ mA}$ $V_{CE} = 10\text{ V}$ $f = 200\text{ MHz}$ $f = 800\text{ MHz}$	19 21	22 7 23 8		dB dB dB dB

\*  $I_B =$  value for which  $I_C = 22\text{ mA}$  at  $V_{CE} = 1\text{ V}$ 

(1) Shield lead not grounded

(2) Shield lead grounded

(3)  $f_p = 202\text{ MHz}$ ,  $f_q = 205\text{ MHz}$ ,  $f_{(2q-p)} = 208\text{ MHz}$ (4)  $f_p = 798\text{ MHz}$ ,  $f_q = 802\text{ MHz}$ ,  $f_{(2q-p)} = 806\text{ MHz}$

SGS-THOMSON

T-31-15

ELECTRICAL CHARACTERISTICS (continued)

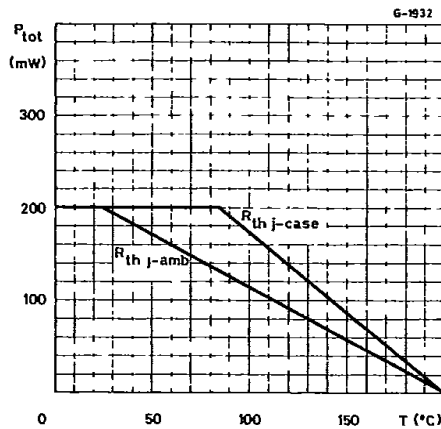
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$P_o$	Output Power	for <b>BFX89</b> $I_C = 8 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $d_{im} = -30 \text{ dB}$ (3) Channel 9 (4) Channel 62		6		mW
		for <b>BFY90</b> $I_C = 14 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $d_m = -30 \text{ dB}$ (3) Channel 9 (4) Channel 62	10	12	12	mW

\*  $I_b$  = value for which  $I_C = 22 \text{ mA}$  at  $V_{CE} = 1 \text{ V}$

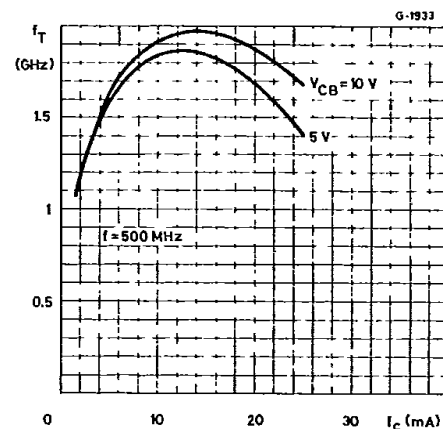
- (1) Shield lead not grounded
- (2) Shield lead grounded

- (3)  $f_p = 202 \text{ MHz}$ ,  $f_q = 205 \text{ MHz}$ ,  $f_{2q,p} = 208 \text{ MHz}$
- (4)  $f_p = 798 \text{ MHz}$ ,  $f_q = 802 \text{ MHz}$ ,  $f_{2q,p} = 806 \text{ MHz}$

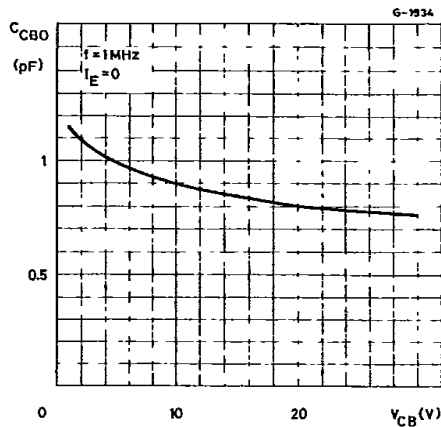
Power Rating Chart.



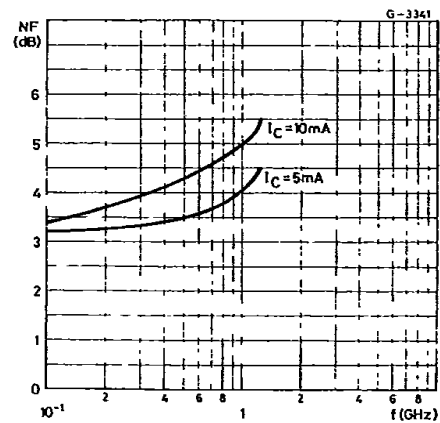
Transition Frequency.



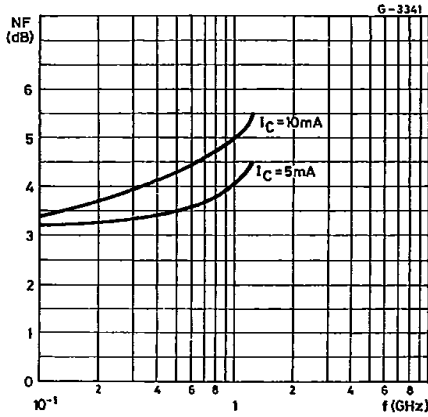
Collector-base Capacitance.



Noise Figure vs. Collector Current.



Noise Figure vs. Frequency.



Forward Transmission Gain vs. Frequency.

